

# NCE3404Y

### NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE3404Y uses advanced trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. This device is suitable for use as a load switch and PWM applications.

#### **Genera Features**

•  $V_{DS} = 30V, I_D = 5.8A$ 

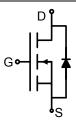
 $R_{DS(ON)}$  < 28m $\Omega$  @  $V_{GS}$ =10V

 $R_{DS(ON)}$  < 40m $\Omega$  @  $V_{GS}$ =4.5V

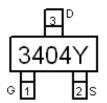
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

## **Application**

- Load switch
- PWM application



Schematic diagram



Marking and pin assignment



SOT-23-3L top view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3404Y	NCE3404Y	SOT-23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	5.8	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	20	Α
Maximum Power Dissipation	P <sub>D</sub>	1.4	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2) R <sub>0JA</sub> 89 °C/W
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## **Electrical Characteristics (T<sub>A</sub>=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μΑ



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## **NCE3404Y**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.2	1.6	2.4	V
Drain-Source On-State Resistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =5A	-	23	28	mΩ
Diain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	27.5	40	mΩ
Forward Transconductance	<b>g</b> FS	$V_{DS}$ =5 $V$ , $I_{D}$ =5 $A$	-	15	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -45\/\/ -0\/	-	255	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz	-	45	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UIVITIZ	-	35	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	4.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =15V, $R_L$ =3 $\Omega$	-	2.5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$	-	14.5	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.5	-	nS
Total Gate Charge	Qg	\/ 45\/  54	-	5.2	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=15V,I_{D}=5A,$ $V_{GS}=10V$	-	0.85	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	1.3	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =5A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.8	Α

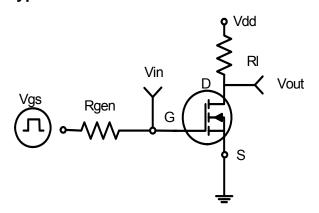
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production

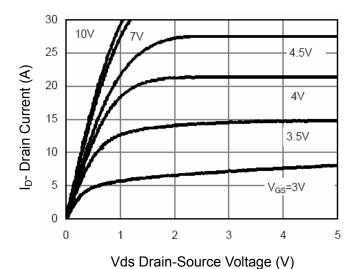
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## **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Output Characteristics** 

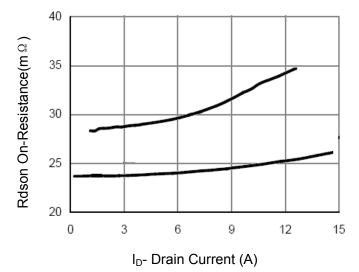


Figure 5 Drain-Source On-Resistance

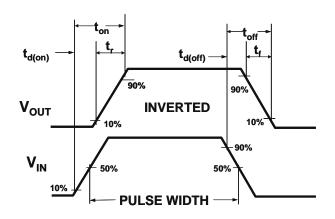
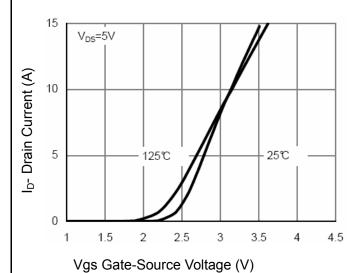


Figure 2:Switching Waveforms



**Figure 4 Transfer Characteristics** 

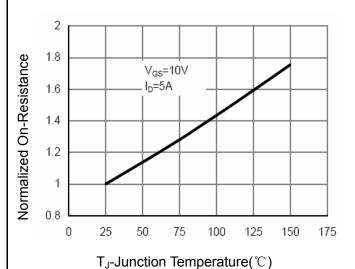
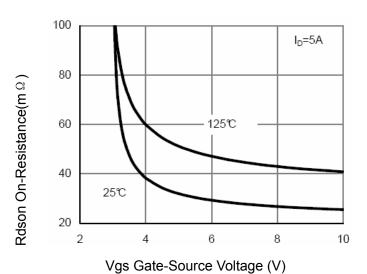


Figure 6 Drain-Source On-Resistance





(N) as Gate-Source Voltage (N) l<sub>D</sub>=5A

Figure7 Rdson vs Vgs

Qg Gate Charge (nC) Figure 9 Gate Charge

5

2

0

1

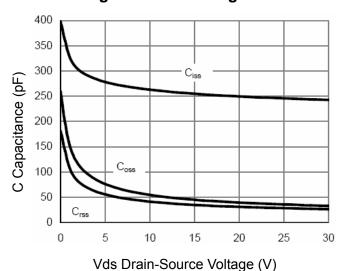


Figure 11 Capacitance vs Vds

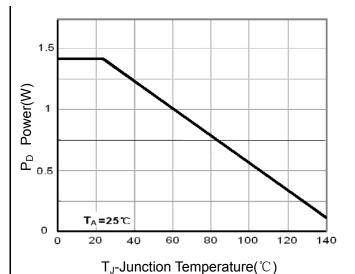


Figure 8 Power Dissipation

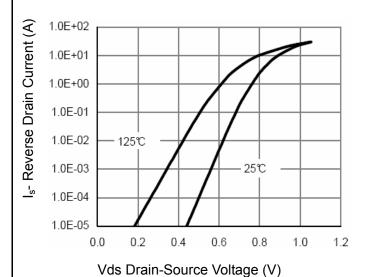
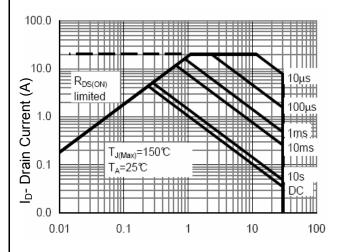
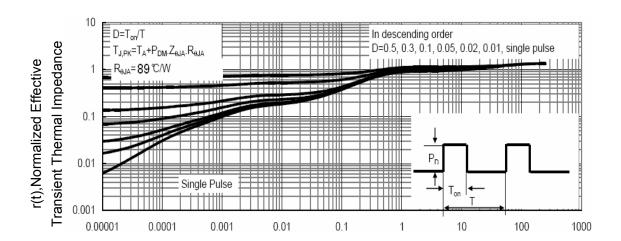


Figure 10 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)
Figure 12 Safe Operation Area

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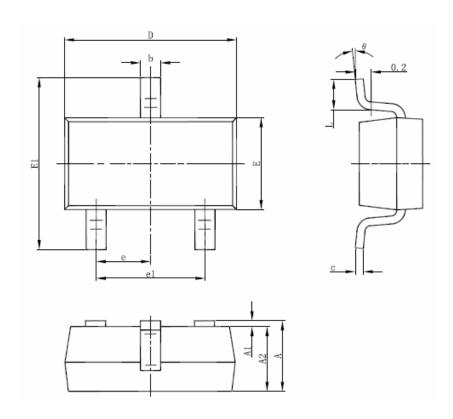


Square Wave Pluse Duration(sec)

Figure 13 Normalized Maximum Transient Thermal Impedance

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## SOT-23-3L Package Information



Symbol	Dimensions Ir	Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950	(BSC)	0.037(	BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

#### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



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